AMT1204P LNA Package Chip



Key Features :

- Frequency range : 6 18GHz
- High gain
- High P-1
- Low cost package
- Applications : wireless communication, transceiver module, radio telecommunication etc.

Description :

AMT1204P is a high performance GaAs LNA, frequency range covers 6 – 18GHz, +5V single supply, typical gain 20dB.

Absolute Maximum Ratings (1a – 25 C)							
Symbol	Parameter	Value	Remark				
Vd	Drain voltage	7V					
Pin	Input signal power	17dBm					
Tch	Operation Temperature	150°C					
Tm	Sintering Temperature	310°C	30s, N ₂ protection				
Tstg	Storage Temperature	-65 ~ +150°C					

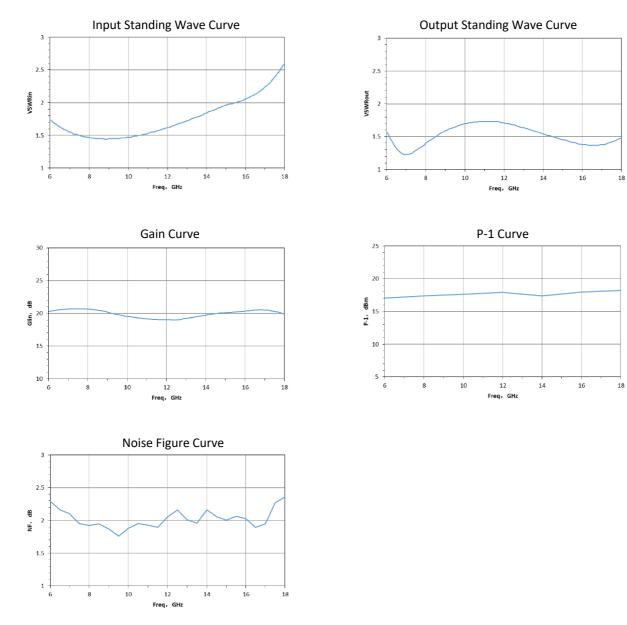
Absolute Maximum Ratings (Ta = 25°C)

[1] Operation outside any of the Absolute Maximum Ratings may cause permanent device damage.

Electrical Characteristics (Ta = 25°C)

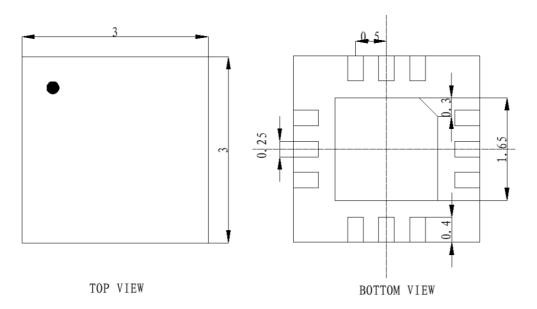
Symbol Parameter		Test Conditions	Value			Unit
			Min	Typical	Max	
G	Gain		-	20	-	dB
NF	Noise figure		-	2	-	dB
Id	Static current	Vd = +5V	-	90	-	mA
VSWRi	Input standing wave	F : 6 ~ 18GHz	-	1.8	2.5	-
VSWRo	Output standing wave		-	1.5	1.8	-
P-1	1dB compression point		15	16@75mA	-	dBm
				18@90mA		

Typical Test Curve

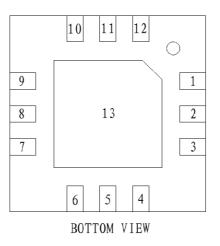


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Dimensions (Unit : mm)



Lead Diagram



Lead	2	8	11	Other
Use	RFin	RFout	+5V Supply	GND

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